NSN 5961-01-041-6717

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-041-6717 **Inclosure Material:** Ceramic **Overall Length:** 0.785 inches **Overall Height:** 0.180 inches **Overall Width:** 0.280 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 collector to emitter voltage/static/base open all transistor and 60.0 collector to base voltage, dc all transistor **Current Rating Per Characteristic:** 50.00 milliamperes collector current, dc all transistor **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: No